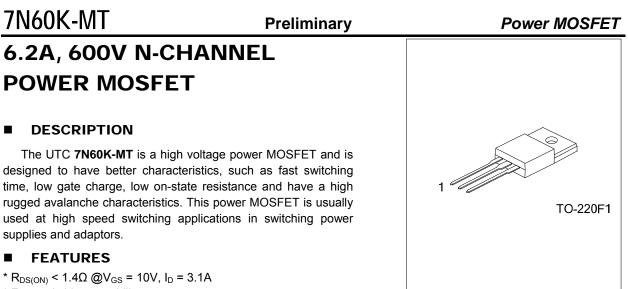
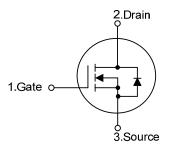


**UTC** UNISONIC TECHNOLOGIES CO., LTD



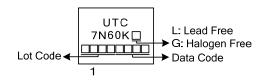
- \* Fast switching capability
- \* Avalanche energy tested
- \* Improved dv/dt capability, high ruggedness



### **ORDERING INFORMATION**

| Ordering Number  |              | Daakaga   | Pin Assignment |   |   | Decking |  |
|--|--------------|---|----------------|---|---|---------|--|
| Lead Free  | Halogen Free | Package   | 1              | 2 | 3 | Packing |  |
| 7N60KL-TF1-T   | 7N60KG-TF1-T | TO-220F1  | G              | D | S | Tube    |  |
| Note: Pin Assignment: G: Gate D: Drain S: Source                       |              |   |                |   |   |         |  |
| 7N60KL-TF1-T<br>(1)Packing Type<br>(2)Package Type<br>(3)Green Package |              | <ul> <li>(1) T: Tube</li> <li>(2) TF1: TO-220F1</li> <li>(3) L: Lead Free, G: Halogen Free and Lead Free</li> </ul> |                |   |   |         |  |

### MARKING



# ABSOLUTE MAXIMUM RATINGS (T<sub>c</sub> = 25°C, unless otherwise specified)

| PARAMETER                          |                        | SYMBOL           | RATINGS    | UNIT |
|------------------------------------|------------------------|------------------|------------|------|
| Drain-Source Voltage               |                        | V <sub>DSS</sub> | 600        | V    |
| Gate-Source Voltage                |                        | V <sub>GSS</sub> | ±30        | V    |
| Avalanche Current (Note 2)         |                        | I <sub>AR</sub>  | 6.2        | Α    |
| Continuous Drain Current           |                        | I <sub>D</sub>   | 6.2        | А    |
| Pulsed Drain Current (Note 2)      |                        | I <sub>DM</sub>  | 24.8       | А    |
| Avalanche Energy                   | Single Pulsed (Note 3) | E <sub>AS</sub>  | 330        | mJ   |
|                                    | Repetitive (Note 2)    | E <sub>AR</sub>  | 13         | mJ   |
| Peak Diode Recovery dv/dt (Note 4) |                        | dv/dt            | 4.5        | ns   |
| Power Dissipation                  |                        | PD               | 48         | W    |
| Junction Temperature               |                        | ТJ               | +150       | °C   |
| Operating Temperature              |                        | T <sub>OPR</sub> | -55 ~ +150 | °C   |
| Storage Temperature                |                        | T <sub>STG</sub> | -55 ~ +150 | °C   |

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Repetitive Rating : Pulse width limited by T

3. L = 18.33mH, I<sub>AS</sub> = 6A, V<sub>DD</sub> = 90V, R<sub>G</sub> = 25  $\Omega$ , Starting T<sub>J</sub> = 25°C

4.  $I_{SD} \le 6.2A$ , di/dt  $\le 200A/\mu s$ ,  $V_{DD} \le BV_{DSS}$ , Starting  $T_J = 25^{\circ}C$ 

## THERMAL DATA

| PARAMETER           | SYMBOL          | RATING | UNIT |  |
|---------------------|-----------------|--------|------|--|
| Junction to Ambient | θ <sub>JA</sub> | 62.5   | °C/W |  |
| Junction to Case    | θ <sub>JC</sub> | 2.6    | °C/W |  |



### ■ ELECTRICAL CHARACTERISTICS (T<sub>J</sub>=25°C, unless otherwise specified)

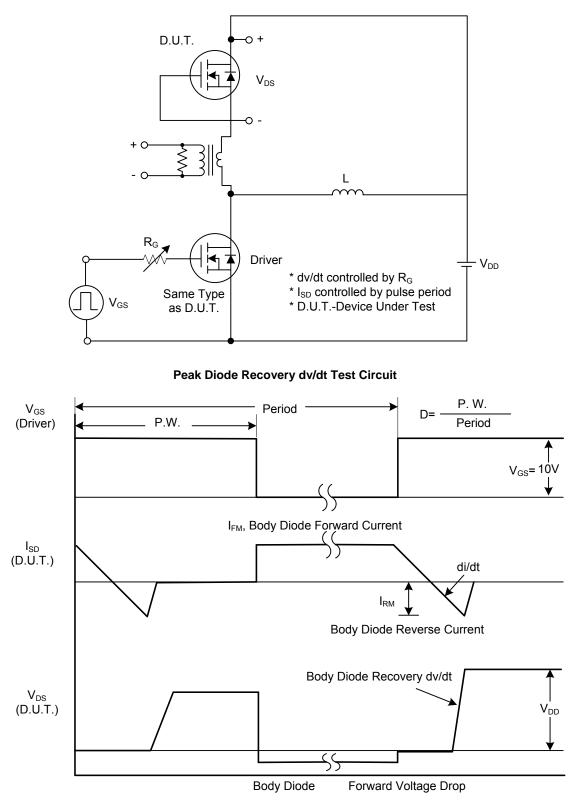
| PARAMETER  |            | SYMBOL   | TEST CONDITIONS   | MIN | TYP  | MAX  | UNIT |
|--|------------|--|---|-----|------|------|------|
| OFF CHARACTERISTICS                                      |            |  |   |     |      |      |      |
| Drain-Source Breakdown Voltage                           |            | BV <sub>DSS</sub>  | V <sub>GS</sub> =0V, I <sub>D</sub> =250µA                                      | 600 |      |      | V    |
| Drain-Source Leakage Current                             |            | I <sub>DSS</sub>   | V <sub>DS</sub> =600V, V <sub>GS</sub> =0V                                      |     |      | 10   | μA   |
|  |            |  | V <sub>DS</sub> =480V, V <sub>GS</sub> =0V, T <sub>J</sub> =125°C               |     |      | 10   | μA   |
|  | Forward    | - I <sub>GSS</sub>   | V <sub>G=</sub> 30V, V <sub>DS</sub> =0V  |     |      | 100  | nA   |
| Gate- Source Leakage Current                             | Reverse    |  | V <sub>GS</sub> =-30V, V <sub>DS</sub> =0V                                      |     |      | -100 | nA   |
| Breakdown Voltage Temperature Co                         | oefficient | $\bigtriangleup BV_{\text{DSS}} / \bigtriangleup T_{\text{J}}$ | I <sub>D</sub> =250μA, Referenced to 25°C                                       |     | 0.53 |      | V/°C |
| ON CHARACTERISTICS                                       |            |  |   |     |      |      |      |
| Gate Threshold Voltage                                   |            | V <sub>GS(TH)</sub>  | V <sub>DS</sub> =V <sub>GS</sub> , Ι <sub>D</sub> =250μΑ                        | 3.0 |      | 5.0  | V    |
| Static Drain-Source On-State Resistance                  |            | R <sub>DS(ON)</sub>  | V <sub>GS</sub> =10V, I <sub>D</sub> =3.1A                                      |     |      | 1.4  | Ω    |
| DYNAMIC CHARACTERISTICS                                  |            |  |   |     |      |      |      |
| Input Capacitance  |            | C <sub>ISS</sub>   |   |     | 540  |      | рF   |
| Output Capacitance                                       |            | Coss   | V <sub>DS</sub> =25V, V <sub>GS</sub> =0V, f=1.0 MHz                            |     | 97   |      | рF   |
| Reverse Transfer Capacitance                             |            | C <sub>RSS</sub>   |   |     | 11   |      | рF   |
| SWITCHING CHARACTERISTICS                                |            |  |   |     |      |      |      |
| Turn-On Delay Time                                       |            | t <sub>D(ON)</sub>   |   |     | 60   |      | ns   |
| Turn-On Rise Time  |            | t <sub>R</sub>   | $V_{DD}$ =30V, $I_{D}$ =0.5A, $R_{G}$ =25 $\Omega$                              |     | 66   |      | ns   |
| Turn-Off Delay Time                                      |            | t <sub>D(OFF)</sub>  | (Note 1, 2)   |     | 120  |      | ns   |
| Turn-Off Fall Time                                       |            | t <sub>F</sub>   |   |     | 64   |      | ns   |
| Total Gate Charge  |            | $Q_G$  |   |     | 23   | 28   | nC   |
| Gate-Source Charge                                       |            | $Q_{GS}$   | V <sub>DS</sub> =50V, I <sub>D</sub> =1.3A, V <sub>GS</sub> =10V<br>(Note 1, 2) |     | 6.7  |      | nC   |
| Gate-Drain Charge  |            | $Q_{GD}$   |   |     | 5.7  |      | nC   |
| DRAIN-SOURCE DIODE CHARAC                                | TERISTIC   | S AND MAXI   | NUM RATINGS   |     |      |      |      |
| Drain-Source Diode Forward Voltage                       |            | V <sub>SD</sub>  | V <sub>GS</sub> =0V, I <sub>S</sub> =6.2 A                                      |     |      | 1.4  | V    |
| Maximum Continuous Drain-Source Diode<br>Forward Current |            | I <sub>S</sub>   |   |     |      | 6.2  | Δ    |
|  |            |  |   |     |      | 0.2  | A    |
| Maximum Pulsed Drain-Source Diode                        |            |  |   |     |      | 24.8 | А    |
| Forward Current  |            | I <sub>SM</sub>  |   |     |      | 24.0 | A    |

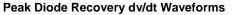
Notes: 1. Pulse Test: Pulse width  $\leq$  300µs, Duty cycle  $\leq$  2%.

2. Essentially independent of operating temperature.



# TEST CIRCUITS AND WAVEFORMS





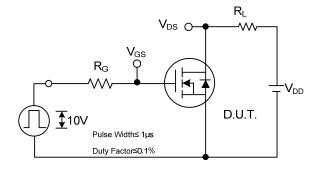


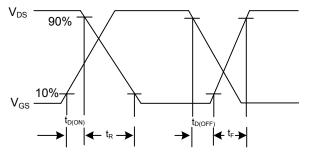
 $\mathsf{V}_{\mathsf{GS}}$ 

10V

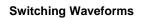
 $Q_{GS}$ 

# ■ TEST CIRCUITS AND WAVEFORMS (Cont.)



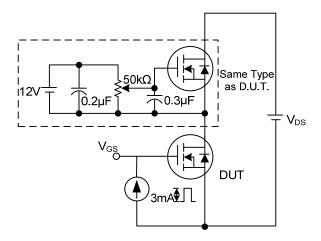


### Switching Test Circuit

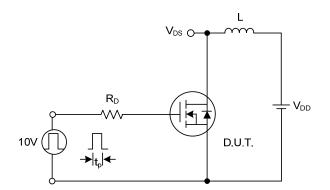


 $\mathsf{Q}_{\mathsf{G}}$ 

 $Q_{GD}$ 



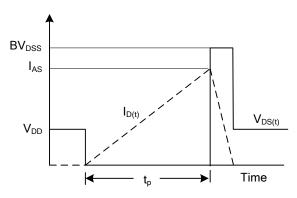
Gate Charge Test Circuit



**Unclamped Inductive Switching Test Circuit** 

**Gate Charge Waveform** 

Charge



**Unclamped Inductive Switching Waveforms** 



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